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## Synthesis and characterization of O-PDI for futuristic optoelectronic and rectifier applications†

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A non-fullerene organic semiconductor, N,N'-di(cis-9-octadecen-1-yl)perylene-3,4,9,10-tetracarboxylic diimide (O-PDI), was synthesized and characterized for its optoelectronic and rectifier applications. O-PDI, derived from the well-known dye perylene-3,4,9,10-tetracarboxylic dianhydride (PTCDA), was spectroscopically characterized for its structure and optical properties using NMR, Fourier-transform infrared (FT-IR), and MALDI-TOF. UV-Vis absorption and fluorescence spectroscopy techniques were employed to study its photophysical properties. Cyclic voltammograms of O-PDI were investigated, and the HOMO and LUMO energy levels of O-PDI were estimated to be -5.86 and -3.57 eV, respectively. Thermal properties were also studied by thermo-gravimetric analysis (TGA). Electrochemical analysis was performed to study its redox behaviour, and the lowest unoccupied molecular orbital and highest occupied molecular orbital energy levels were calculated. The electrical properties of the Al/P-C-Si/O-PDI/Ag device were investigated. The device's dark current–voltage (I–V) characteristics were measured at room temperature. Rectifying behaviour was observed in the device at room temperature with a rectification ratio of  $\sim$  3470 $@$   $\pm$  2 V. The device parameters, including the ideality factor, barrier height, series, and shunt resistances, were extracted using the conventional I-V characterization method. The parameters, such as cut-off voltage ( $\sim$  0.79 V), reverse saturation current ( $l_0$ ) ( $\sim$  2.59 nA cm<sup>-2</sup>), barrier height ( $\phi_{\rm b}$ ) (~0.89 eV), ideality factor (n) (~2.55), shunt resistance (R<sub>sh</sub>) (~24.21 MΩ), and series resistance  $(R_s)$  ( $\sim$  2823  $\Omega$ ), were determined at room temperature. PAPER<br>
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## 1. Introduction

Over the past few decades, organic semiconductors, widely acknowledged as essential electronic components, have undergone thorough investigation driven both by market demands and the potential for advancements. This exploration has led to the creation of various applications, such as organic lightemitting diodes (OLEDs), organic solar cells (OSCs), and organic field effect transistors  $(OFETs)$ .<sup>1–3</sup> Organic semiconductors are categorized into two types: p-type and n-type. Comparatively, there are fewer n-type materials than the p-type, focusing predominantly on fullerene and non-fullerene-based materials. Fullerenes have certain drawbacks, including a rigid bandgap, limited chemical reactivity, and elevated costs, thereby impacting their practical application. Consequently, there has been a

shift towards non-fullerene materials (NFMs). Among the array of NFMs, perylene and its derivatives have garnered significant attention due to their noteworthy properties, encompassing high molar absorptivity, adjustable absorption ranges, elevated quantum yields of fluorescence, robust electron affinity, and impressive photochemical and thermal stabilities. $4-6$ 

Perylene diimides (PDIs) exhibit promising properties such as strong molar absorptivity in the range of  $\sim$  400–450 nm (B band) and  $\sim$  500–700 nm (Q band) due to their extended conjugated  $\pi$  systems.<sup>7,8</sup> The properties of PDIs have been tuned by modifying the substituents at the imide nitrogen and bay positions of the perylene core. $9,10$  Researchers have reported various types of amine substitutions at the imide position to enhance solubility and morphology, such as the long aliphatic chain shown in Fig. 1. For instance, 1-dodecyl amine helps enhance solubility, leading to 1D nanofiber formation. However, due to the 1D structure, there is significant  $\pi$ – $\pi$  stacking between them.<sup>11</sup> N-(3-Aminopropyl) imidazole reduces crystallinity and aggregation but improves charge transport.12 The small secondary amine 2,4-dimethylpent-3-ylamine does not exhibit good solubility but enhances fluorescence in solids and liquids.<sup>13</sup> Consequently, researchers employed much



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larger secondary amine molecules such as 2-ethylhexan-1-amine, 1-pentylhexyl, and 1-hexylheptyl at the imide position to disrupt intermolecular  $\pi-\pi$  stacking between PDI molecules and improve solubility in organic solvents such as chloroform  $(CHCl<sub>3</sub>)$ , dichloromethane (DCM), toluene, dimethyl sulfoxide (DMSO), and tetrahydrofuran  $\text{(THF)}$ .<sup>14–16</sup> Additionally, 3-(dimethylamino)-1propylamine favours  $\pi-\pi$  stacking out of the plane and is associated with lamellar orientation. Its oxide also helps tune PDI's work function.<sup>17,18</sup> Based on the literature, as discussed above, optimizing the side chain is a widely adopted strategy in organic semiconductor materials to enhance solubility and solid-state properties.

Schottky diodes, represent fundamental and ubiquitous electronic components in semiconductor applications, exhibiting rectifying behavior.<sup>19</sup> These diodes encompass p-type and n-type semiconductors, and a pn-junction is formed at the interface of the n-and p-type semiconductors, which meticulously govern the unidirectional current flow.<sup>20</sup> The inherent properties of Schottky diodes crucially depend upon the interface properties of n- and p-type semiconductors at the junction, exerting a profound impact on characteristics parameters such as the ideality factor  $(n)$ , barrier height  $(\phi_b)$ , and series resistance  $(R_s)$  of the Schottky diodes. Heterojunction devices wherein organic semiconductors are deposited on silicon, forming a pn-junction have been reported previously.<sup>21,22</sup> This modification influences certain electrical parameters of rectifying devices. Numerous efforts have been undertaken to achieve the modification and continuous control of the barrier height using organic semiconductors. The heterojunction device is expected to provide a flexible choice of emitter and carrier transport materials, offering a distinctive approach to constructing high-performance electronic devices that capitalize on the advantages of both inorganic and organic semiconductors. $^{23}$ 

Herein, a novel n-type organic semiconductor (perylene derivative) was synthesized for the fabrication of a heterojunction diode. An aliphatic chain (fatty amine long chain) was introduced at the imide position, inspired by the previous report on introducing aromatic systems at the imide position

to increase solubility. The synthesis and characterization of N,N'-di(cis-9-octadecen-1-yl)perylene-3,4,9,10-tetracarboxylic diimide (O-PDI) are being reported. Ag/O-PDI/p-Si/Al Schottky barrier diode was fabricated, and the heterojunction was formed between p-type crystalline silicon and n-type organic semiconductor (O-PDI). Current-voltage (I-V) characteristics were measured at room temperature under dark conditions. Moreover, electrical parameters such as ideality factor  $(n)$ , barrier height  $(\phi_b)$ , and series resistance  $(R_s)$  were evaluated from *I-V* characteristics.

## 2. Experiment section

#### 2.1 Chemicals and instruments

All chemicals and reagents were purchased from Alfa-Asher, and Sigma-Aldrich, and solvents were purified by distillation before use. UV-visible absorption spectra were recorded on a UV-2401PC SHIMADZU spectrometer in different solvents using 1 mg/3 ml solution. For the film fabrication, 3 mg ml<sup>-1</sup> solution was spin-coated at  $\sim$  1000 rpm for  $\sim$  30 s on 2  $\times$  2 cm clean glass substrates and annealed at  $\sim$  100 °C for 10 min. Fourier transform infrared spectroscopy (FT-IR) was recorded on a PerkinElmer FT-IR instrument using KBr pallets and a spectrum range from 4000 to 400  $\text{cm}^{-1}$ . <sup>1</sup>H NMR and <sup>13</sup>C NMR were recorded, CDCl<sub>3</sub> was used as the solvent, and tetramethylsilane (TMS) was used as the reference material. The electrochemical nature was analysed by cyclic voltammetry (CV) through three electrochemical cell configurations, and a glassy carbon disc electrode was used as the working electrode while a thin gold wire was used as a counter electrode, a non-aqueous Ag/AgCl reference electrode was employed as the reference electrode. The electrochemical measurements were carried out using 0.1 M tetrabutylammoniumhexafluorophosphate  $(Bu<sub>4</sub>NPF<sub>6</sub>)$  as the electrolyte in anhydrous dichloromethane used as the solvent at room temperature under the scan rate  $\sim$  100  $\text{mV}^{-1}.$ 

#### 2.2 Synthesis procedure of  $N, N'$ -di(cis-9-octadecen-1yl)perylene-3,4,9,10-tetracarboxylic diimide (O-PDI)

500 mg (1.27 mmol) of 3,4:9,10-perylene tetracarboxylic dianhydride (PTCDA) was placed in a vial with 2.5 g of imidazole. Approximately  $\sim 800$  mg (2.99 mmol) of oleylamine (cis-9octadecen-1-amine) was then added to the mixture. The vial was sealed, and nitrogen gas was purged into the reaction mixture. The reaction was stirred at approximately  $\sim$  120 °C for about 7 hours, $11$  resulting in the formation of a dark red solid. The reaction mixture was subsequently washed four times with 50 ml of methanol (since imidazole and oleylamine are highly soluble in methanol) using a centrifuge. A red solid product was obtained with a yield of 1.0 g (88% yield) as shown in Fig. 2. FT-IR  $(\tilde{\nu}~~{\rm cm}^{-1})$  = 2922 (C–H), 2850 (C–H), 1693  $(-C=0)$ , 1651  $(-C=0)$ , 1591  $(-C=C-)$ , 1577  $(-C=C-)$ , 1465 (CH<sub>3</sub> bend), 1438 (CH<sub>2</sub> bend), 1404 (C-N<sub>str</sub>), 1377 (CH<sub>3</sub> sym), 746  $(C=C_{cis}$  alkene), 727 (C= $C_{cis}$  alkene), 630 (-N-C= $O_{bend}$ ), 435 (C–N–C<sub>bend</sub>). <sup>1</sup>H NMR (400 MHz, chloroform-D)  $\delta$  8.4 (d, 4H), 8.2 (d, 4H), 5.35 (m, 4H), 4.14 (t, 4H), 1.98 (m, 8H), 1.77 (m, 4H), 1.42 (m, 4H), 1.25–1.29 (m, 40H), 0.86 (t, 6H). 13C NMR (101 MHz, CDCl<sub>3</sub>) δ 161.84, 132.70, 129.73, 129.34, 128.91, 128.83, 127.75, 124.58, 122.00, 121.55, 58.50, 39.68, 37.12, 31.60, 30.88, 30.77, 30.22, 28.76, 28.71, 28.67, 28.65, 28.60, 28.51, 28.40, 28.36, 28.30, 28.18, 27.05, 26.21, 26.18, 21.66, 13.10. MALDI-TOF:  $m/z = 890.2427$  g calculated for  $C_{60}H_{78}N_2O_4 = 890.640$ .

#### 2.3 Device fabrication

P-Crystalline silicon wafer was sonicated in a diluted solution of HF (1 : 10) for 5 minutes for the removal of the oxide layer on the surface of the silicon wafer, then with acetone for  $\sim$  5 min and later dried with a purging by the stream of  $N_2$  gas. Al was thermally deposited on the back surface of the dried silicon wafer by thermal evaporation. On the front surface,  $\sim$  120 nm of O-PDI was thermally deposited at the rate of  $\sim$  0.1 nm s<sup>-1</sup> under the  $\sim$ 10<sup>-5</sup> mbar pressure, and the thickness of the film was monitored using the quartz crystal. Further,  $\sim$  100 nm of silver (Ag) fingers were thermally deposited on the O-PDI for the top contact.

## 3. Results and discussion

In this work, we synthesized a small molecule consisting of perylene diimide substituted with a fatty amine through a nucleophilic substitution reaction at the imide position. We studied its optical properties, thermal stability, electrochemical characteristics, and self-assembly properties. It should be noted that PTCDA has two active imide substitution positions. In response, oleylamine  $(\omega^{-9}$  long aliphatic fatty amine) serves as an excellent nucleophile, attacking the anhydride group present in PTCDA and forming perylene diimide as the final product, O-PDI (depicted in Fig. 2a). This product was isolated in the solid form, displaying a dark red color, as shown in Fig. 2b. Structural properties were characterized using FT-IR and NMR spectroscopy. Fig. S1 (ESI†) illustrates the FT-IR spectra of O-PDI, revealing two major and sharp peaks at  $\sim$  2922  $\rm cm^{-1}$  and  $\sim$  2850  $\rm cm^{-1}$ ,



Fig. 2 (a) Synthetic route of O-PDI, (b) synthesized powder.

which were not present in the parent molecule (PTCDA) and are indicative of alkyl C–H stretching. This suggests the attachment of the long aliphatic chain of carbon from oleylamine. Perylene diimide showed the disappearance of the dianhydride  $C=O$ stretching peak of the parent molecule at  $\sim$ 1772 cm<sup>-1</sup> and  $\sim$ 1754 cm<sup>-1</sup>, with the appearance of new peaks at  $\sim$ 1693 cm<sup>-1</sup> and  $\sim$  1651 cm<sup>-1</sup>, which belong to the imide C=O group. This confirmed the introduction of the imide group into the perylene molecule. NMR spectroscopy was used to validate the plausible structure of O-PDI. Fig. S2a (ESI<sup>†</sup>) depicts the <sup>1</sup>H NMR spectra, and Fig. S2b (ESI†) shows the  $^{13}$ C NMR spectra. The proton NMR spectrum revealed highly deshielded eight protons at  $\sim$  8.4 ppm

Table 1 Solubility of O-PDI in different solvents

Solubility of O-PDI in different solvents Table 1			coefficient is considered constant, and the path length is fixed	
S. no.	Solvent	O-PDI	Consequently, the material's light absorption is directly pro	
1	Dichloromethane	Soluble	portional to its molar concentration in a given solvent, as	
3	Chlorobenzene	Soluble	shown in eqn $(2)$ <sup>15,16</sup> This implies that a higher hyperchromic	
$\overline{4}$	o-Xylene	Soluble with dispersed particles	shift corresponds to a higher concentration, indicating better	
5	Toluene	Soluble with dispersed particles	solubility of the solvent.	
6	<b>THF</b>	Soluble with dispersed particles		
$\overline{7}$	Diphenyl ether	Soluble	Absorption spectra of O-PDI were recorded at a concen-	
8	1,4-Dioxane	Slightly soluble	tration of approximately $\sim 0.187$ µM in various solvents. The	
9	Methyl iso-butyl ketone	Partially soluble	solvent selection was based on Table 1, and Fig. 3a displays that	
10	<b>NMP</b>	Dispersed particles	O-PDI exhibited superior solubility in the investigated solvents	
11	<b>DMF</b>	Dispersed particles		
12	<b>DMSO</b>	Dispersed particles	such as dichloromethane, chlorobenzene, o-xylene, toluene, and	
13	Ethyl acetate	Insoluble	tetrahydrofuran. Chlorobenzene displayed the highest hyperchro	
14	Acetonitrile	Insoluble	mic shift and molar extinction coefficient ( $\epsilon = 92\,731 \, \text{M}^{-1} \, \text{cm}^{-1}$ )	
15	Ethanol	Insoluble		
16	Methanol	Insoluble	as shown in Table 2. Other solvents, including o-xylene	
17	Isopropyl alcohol	Insoluble	$(\epsilon = 63\,109\,M^{-1}\,cm^{-1})$ , dichloromethane $(\epsilon = 48\,140\,M^{-1}\,cm^{-1})$	
18 19	<i>n</i> -Butyl alcohol	Insoluble	toluene $(\epsilon = 47974 \text{ M}^{-1} \text{ cm}^{-1}),$ THF $(\epsilon = 46242 \text{ M}^{-1} \text{ cm}^{-1})$	
	$n$ -Hexane $n$ -Heptane	Insoluble Insoluble		
20 21	Water	Insoluble	<i>N</i> -methyl 2-pyrrolidone ( $\varepsilon$ = 23 260 M <sup>-1</sup> cm <sup>-1</sup> ), diphenyl ether	
			$(\varepsilon = 10033 \text{ M}^{-1} \text{ cm}^{-1})$ , methyl iso-butyl ketone $(\varepsilon = 8345 \text{ M}^{-1} \text{ cm}^{-1})$	
		and $\sim$ 8.2 ppm due to the carbonyl group and the perylene core,	1,4-dioxane $(\epsilon = 8056 \,\mathrm{M}^{-1} \,\mathrm{cm}^{-1})$ , and dimethylformamide	
		with outer field protons being more deshielded. The alkyl group		
		protons exhibit chemical shift values ranging from $\sim$ 2.0 ppm to	(a)	
		$\sim$ 0.80 ppm. Solubility is a critical factor for potential applications,	-Chlorobenzene	
		and we prepared a $\sim$ 3 mg ml <sup>-1</sup> solution in various solvents to	$-\mathbf{DCM}$ 1.6	
		assess the solubility of O-PDI. Our observations, shown in Table 1,	$\longrightarrow$ 1-4 Dioxane	
			$\blacksquare$ DMF	
		indicate that O-PDI is readily soluble in benzene-based and halo-	$\longrightarrow$ DPE	
		group solvents, with further details discussed in the table. We	$\longrightarrow$ MIBK	
		found that O-PDI is soluble in benzene-based solvents (chloroben-	$\longrightarrow$ NMP	
		zene, toluene, o-xylene, and diphenyl ether) as well as polar aprotic	$\blacksquare$ THF	
			— Toluene	
		solvents (dichloromethane, THF, 1,4-dioxane, MIBK, NMP, DMF,	$\longrightarrow o$ -Xylene	
		and DMSO) but insoluble in polar protic solvents (n-butanol,		
	polar solvents ( $n$ -hexane and $n$ -heptane).	isopropyl alcohol, ethanol, methanol, and water) as well as non-	$\begin{align} \mathbf{a} \cdot \mathbf{b} = \mathbf{a} \cdot \mathbf{b} = \mathbf{a} \cdot \mathbf{b} = \mathbf{a} \end{align}$	

#### 3.1 Ultraviolet spectroscopy (UV)

To determine the optical properties of O-PDI, we need to understand the molecule's solubility in different solvents, as discussed in Table 1. However, the solubility table does not indicate which solvent exhibits superior solubility. Therefore, we employed the Beer–Lambert law, as shown in eqn (1) (absorbance of a material depends on both the path length and the concentration of the species)

$$
A = \epsilon cl \tag{1}
$$

$$
A \, \propto \, c \tag{2}
$$

In eqn (1), A represents absorbance (the amount of light absorbed by the sample at a particular wavelength),  $c$  is the molar concentration of the absorbing material,  $l$  is the path length through which light passes in the solution, and  $\epsilon$  is the molar extinction coefficient, which describes how strongly a chemical species absorbs incident light at a specific wavelength. This coefficient is an intrinsic property of the chemical species. Due to its intrinsic nature, the molar extinction



Fig. 3 (a) Absorption spectra with different solvents. (b) Normalized absorption spectra with other solvents.

Table 2 Tabulated optical absorption data

Solvent	$\lambda_{\rm abs}$ (nm)		$\epsilon$ (M <sup>-1</sup> cm <sup>-1</sup> ) Band gap (eV)
Chlorobenzene	527, 490, 459	92731	$\sim 2.29$
o-Xylene	526, 490, 458	63109	$\sim 2.29$
Dichloromethane	523, 486, 456	48140	$\sim$ 2.31
Toluene	525, 489, 457	47974	$\sim$ 2.30
Tetrahydrofuran	520, 484, 453	46242	$\sim 2.33$
N-Methyl 2-pyrrolidone	524, 489, 460	23 260	$\sim$ 2.30
Diphenyl ether	529, 493, 461	10033	$\sim$ 2.28
Methyl iso-butyl ketone	518, 482, 451	8345	$\sim$ 2.33
1,4-Dioxane	520, 485, 453	8056	$\sim$ 2.33
Dimethylformamide	524, 488, 457	414	$\sim$ 2.30

 $(\epsilon = 414 \,\mathrm{M}^{-1} \,\mathrm{cm}^{-1})$ , exhibited varying molar extinction coefficients for O-PDI. The molar extinction coefficient of PDI can vary with different solvents due to a combination of factors, including solute–solvent interactions, aggregation, conformational changes, and concentration.

In the case of benzene-based solvents, they can easily interact with O-PDI due to  $\pi-\pi$  interactions (solute–solvent interactions), which occur between the conjugated systems. These interactions can lead to more pronounced aggregation and hyperchromic shift. On the other hand, polar aprotic solvents (DMF, 1,4-dioxane, and MIBK) exhibited lower molar extinction coefficients due to the dispersed particles, as discussed in Table 1. We chose chlorobenzene as the base solvent due to its excellent solubility.

Fig. 3b illustrates the normalized absorption spectrum of O-PDI in different solvents. We observed slight shifts in the peaks of O-PDI in different solvents, which can be attributed to the solvatochromic effect. These shifts depend on how the solvent interacts with the solute or the polarity of the solvent. Among the solvents listed in Table 2, diphenyl ether exhibited the highest bathochromic shift (red shift). Notably, benzene-based solvents displayed the highest bathochromic shifts, with the order being diphenyl ether  $>$  chlorobenzene  $>$  o-xylene  $>$ toluene, owing to  $\pi-\pi$  interactions (solute–solvent interactions).<sup>15</sup> In these solvents, the spectrum of O-PDI featured three typical absorption peaks, confirming that there were no significant structural changes in the core structure of perylene diimide due to imide substitution.

The absorption peaks of O-PDI (Fig. 4) were observed at approximately 527 nm, 490 nm, and 459 nm, corresponding to the vibronic absorption bands for the  $0 \rightarrow 0$ ,  $0 \rightarrow 1$ , and  $0 \rightarrow 2$ transitions, respectively. These transitions are associated with the  $\pi-\pi^*$  electronic transition of monomeric perylene diimide in chlorobenzene. In the electronic absorption of perylene diimide, there was a notable coupling with vibronic features corresponding to  $v = 0 \rightarrow v' = 0$ , 1 and 2 transitions, where v and  $v'$  represent quantum vibrational numbers for the ground and excited states, respectively. However, as the monomer begins to self-aggregate, we observed a hyperchromic shift in the  $0 \rightarrow 2$ and  $0 \rightarrow 1$  transitions, accompanied by a loss of fine vibronic structure and a broadening of the spectra.<sup>17</sup> This phenomenon indicates that the perylene diimide molecular scaffolds facilitate  $\pi-\pi$  intermolecular interactions between neighbouring





molecules.<sup>18</sup> In the case of the film, the absorption spectrum is broadened, and the absorption peak undergoes a bathochromic shift of  $\sim$ 39 nm compared to that in the solution, as shown in Fig. 4. This broader spectrum suggests stronger  $\pi-\pi$  interchain associations in the film compared to those in the solution. $^{24}$ 

#### 3.2 Tauc plot

The band gap energy is essential for predicting the photochemical and photophysical properties of a material. The band gap energy of organic materials is used to determine the energy required to excite an electron from the higher occupied molecular orbital (HOMO) to the lower unoccupied molecular orbital (LUMO). In particular, Tauc introduced a method in 1966 to calculate the band gap energy using optical absorption spectra. The absorption spectra of O-PDI were employed to calculate the band gap energy with the help of Tauc's relation: $^{25}$ 

$$
\alpha E = (E - E_{g})^{m} \tag{3}
$$

$$
A = -\ln\left(\frac{I}{I_0}\right) = \alpha d \tag{4}
$$

By comparing eqn (3) and (4), we obtain:

$$
(AE/d)^{1/m} = (E - Eg)
$$
\n(5)

$$
E - (AE/d)^{1/m} = Eg
$$
 (6)

$$
E - (\alpha h\nu)^{1/m} = E_{\rm g} \tag{7}
$$

In these equations, A represents the absorption of O-PDI,  $\alpha$  is the absorption coefficient of O-PDI,  $E$  is the energy of the photon,  $E<sub>g</sub>$  is the band gap energy, d is the thickness of O-PDI (film or solution), and  $m$  is a factor that depends on the electronic transition between the highest occupied molecular orbital (HOMO) and the lowest unoccupied molecular orbital (LUMO). Two types of transitions are direct transition  $(m = 1/2)$ and indirect transition  $(m = 2)$ . The perylene diimide family mostly follows the direct transition model to determine the value of  $E_g$ . Hence,  $(\alpha h v)^2$  is plotted against E, as shown in Fig. 5(a). However, the band gap of O-PDI is determined by extrapolating the linear portion of the  $(\alpha h v)^2$  versus E to zero, resulting in an energy band gap value of approximately 2.29 eV.



Fig. 5 (a) Tauc plot of O-PDI in chlorobenzene. (b) Tauc plot of the solution of O-PDI with different solvents.

On the other hand, in Fig. 5(b), we discuss the Tauc plot of O-PDI with different solvents and find that the solvent also affects the band gap value. It follows the same pattern as the absorption spectrum of the different solvents. All the band gap values and  $\lambda_{\text{max}}$  are discussed in Table 2.

#### 3.3 Photoluminescence spectroscopy

Emission spectra (Fig. 6) were acquired under low chlorobenzene concentrations, revealing that O-PDI displayed a mirror image of the absorption spectra, indicating the absence of aggregation.<sup>26</sup> Three distinct emission bands were observed with peaks at  $\sim$  541 nm,  $\sim$  578 nm, and  $\sim$  627 nm, corresponding to the  $0 \rightarrow 0$ ,  $1 \rightarrow 0$ , and  $2 \rightarrow 0$  electron transitions, respectively. An evident, Stokes shift of  $\sim$  14 nm was observed, which could be attributed to the  $\pi-\pi$  interactions occurring between the aromatic solvent and O-PDI molecules.

#### 3.4 Cyclic voltammetry

The electrochemical nature of electron and hole transport materials was investigated by cyclic voltammetry (CV), which



Fig. 6 Comparison of photoluminescence spectrum (PL) and absorption spectrum of O-PDI.

is used to study the reversible redox characteristics and electrochemical stability and calculate the HOMO–LUMO energy levels. The cyclic voltammetry curve of O-PDI is shown in Fig. 7, where O-PDI did not show any observable oxidation potential, as such, the HOMO energy level was not calculated from cyclic voltammetry and indicated the reduction potential ( $E_{\text{onset}}^{\text{red}}$  – 0.59 V). The equation,  $E_{\text{LUMO}}$  =  $-[E_{\text{onset}}^{\text{red}}]$  $-E_{\text{Fc/Fc}^+}$  + 4.8] eV,<sup>27</sup> was used to calculate the LUMO energy level, and the onsets of the oxidation and reduction potentials were determined against  $Fc/Fc^+$  as the internal standard. Assuming the absolute energy level of  $Fc/Fc^+$  to be 4.8 eV below a vacuum, and  $E_{\text{half}}$  of ferrocene to be 0.633 V in dichloromethane and the LUMO level was calculated to be -3.57 eV for O-DPI and the HOMO level was calculated using the equation  $E_{\rm HOMO}$  =  $E_{\rm LUMO}$   $-$  bandgap was determined with the help of the absorption spectra. Hence the HOMO level of OPDI was  $-5.86$  eV.



Fig. 7 Cyclic voltamentric graph of O-PDI.

#### 3.5 Thermal gravimetric analysis (TGA)

The TGA thermogram of O-PDI is shown in Fig. 8. The measured temperature characteristics, such as  $T_{on}$  (decomposition temperature onset), and  $T_{10}$  (temperature for 10% loss), were determined from TGA. We observed that  $T_{on}$  of O-PDI was up to  $\sim$  200 °C, which showed that O-PDI is thermally stable, and there is no weight loss in the range of  $100-175$  °C, which indicates the absence of moisture in the material, $28$  showing ~10% weight loss up to  $T_{10}$  ~ 400 °C, after that its started losing its characteristics properties, indicating very high thermal stability, confirming that OPDI is a very suitable candidate for electronic devices.

#### 3.6 X-ray diffraction patterns (XRD)

We performed XRD studies on the solid (a) and thin film (b) samples, as depicted in Fig. 9. The thin film samples were dropcast onto cleaned glass substrates from a chlorobenzene solution and annealed at 120 $\degree$ C for 30 minutes. The diffractograms displayed distinct features. Curve (a) showed characteristic peaks at  $2\theta = 20^{\circ}-30^{\circ}$ , indicating the low crystallinity of solid O-PDI. In contrast, curve (b) exhibited a halo pattern, suggesting that the film was amorphous, with a highly disordered arrangement of molecules.<sup>11</sup> This amorphous nature is most likely due to the drop-casting process, where the rapid drying of the film leads to increased disorder.

#### 3.7. Rectifier application

Current–voltage  $(I-V)$  measurement helps in the study of p–n junction properties. Furthermore, the mechanism of conduction through the device can be analysed through I–V measurements. The reverse  $(-3 \text{ to } 0 \text{ V})$  and forward  $(0-3 \text{ V})$  bias  $I-V$ characteristics are shown in Fig. 10(b) for Al/P-c-Si/O-PDI/Ag. The nonlinear/asymmetric behaviour observed from the I–V curves indicates the rectifying behaviour of the device resulting from the formation of a pn-junction between p-type silicon and O-PDI. The rectification ratio (RR), the ratio of the forward





Fig. 9 Comparative X-ray diffraction of O-PDI in (a) solid and (b) film.

current to the reverse current, $29$  was calculated at room temperature, showing the value  $\sim$  3470@  $\pm$  2 V, as shown in Fig. 10(c), which is higher than that reported so far for other PDI-based devices (Table 3). The thermionic emission (TE) theory is used to comprehend the behaviour of the heterojunction, and current can be expressed as per eqn  $(8)$ .<sup>30,31</sup>

$$
I = I_0 \left[ e^{\left(\frac{q(V - \text{IR}_s)}{nkT}\right) - 1} \right]
$$
 (8)

$$
I_0 = AA^* T^2 e^{\left(\frac{-q\phi_b}{kT}\right)} \tag{9}
$$

The barrier height is obtained from eqn (9), and can be written as

$$
\phi_{\rm b} = \frac{kT}{q} \ln \left( \frac{AA^* T^2}{I_0} \right) \tag{10}
$$

$$
A^* = \frac{4\pi m^* k^2}{h^3}
$$

The equation incorporates several variables and constants:  $q$  represents the elementary charge (electron),  $V$  signifies the applied voltage across the hetero-junction,  $k$  denotes Boltzmann's constant  $(1.38 \times 10^{-23} \text{ J K}^{-1})$ , T represents the absolute temperature in kelvin, A represents the effective area of the device (approximately  $\sim$  1.5 cm<sup>2</sup>),  $A^*$  is the Richardson constant specific to p-c-silicon and is equal to 32 A cm<sup>-2</sup> K<sup>-2</sup>, Fig. 8 Thermal-gravimetric analysis of O-PDI. and  $m^*$  represents the effective mass for holes perpendicular to



Fig. 10 Heterojunction device Al/P-c-Si/O-PDI/Ag fabricated using synthesized O-PDI and all the analysis carried out at room temperature under the dark condition, (a) schematic of the heterojunction device, (b) I-V characteristics at room temperature and the inset shows the actual device from the back and front side, (c) rectification curve of device, (d) semi-logarithmic (I–V) characteristics, and (e) junction resistance vs. voltage.

the layer.<sup>22,32,33</sup>  $I_0$  can be determined from the y-intercept of the ln I vs. V plot at  $V = 0$ , as shown in Fig. 10(d). Solving eqn 8 allows for the derivation of the expression for the ideality factor  $(n)$ .

$$
n = \frac{q}{kT} \frac{\mathrm{d}V}{\mathrm{d}(\ln I)}\tag{11}
$$

The ideality factor  $(n)$  of a diode can be determined by analysing the slope of the linear region in the forward bias current of the  $\ln I$  vs. *V* curve. In an ideal diode, *n* is expected to be unity,

indicating ideal behaviour.  $n$  is a parameter that reflects the uniformity of the Schottky barrier in the hetero-junction. A more uniform interface between materials will result in the n value closer to unity. However, the device of O-PDI shows the ideality factor of  $\sim$  2.55, reverse saturation current (I<sub>0</sub>) of  $\sim$  2.59 nA cm<sup>-2</sup>, and barrier height ( $\phi$ <sub>b</sub>) of the diode was calculated as  $\sim$  0.89 eV. Junction resistances are critical for understanding the electrical parameters of heterojunction devices. In particular, series resistance  $(R<sub>s</sub>)$  and shunt resistance  $(R_{\rm sh})$  are widely studied in these devices. The values of  $R_{\rm s}$  Table 3 Comparison of electrical properties of various heterojunction devices



and  $R_{\rm sh}$  were determined by analyzing the junction resistance  $(R_i = \partial V/\partial I)$  versus the bias voltage curve, as shown in Fig. 10(e). In the forward bias region, the minima of the  $R_i$  vs. V curve corresponds to the series resistance  $(R_s) \sim 2823 \Omega$ , in the reverse bias region, the maxima of the  $R_i$  vs. V curve represents the shunt resistance  $(R_{\rm sh}) \sim 24.21$  M $\Omega$ .

Herein, it is essential to mention that the demonstration of the use of O-PDI in rectifiers is a part of the motivation for hybrid nanoelectronics, mainly based on observing nonlinear charge transport in organic molecules grafted on a silicon substrate. This is the basis of molecular electronics, such as molecular diodes, tunnel diodes, and molecular transistors. Various techniques, such as self-assembled monolayers, Langmuir–Blodgett, or metal/molecule/metal, can deposit the assembly of organic molecules on a solid substrate. Silicon is better as one can tailor the surface potential for promising hybrid molecular devices. The threshold voltage for rectification can be controlled by changing the electronic structure of organic molecules. The rectification ratio decides the quality of the rectifier fabricated in hybrid structures. The rectification property is the consequence of resonant transport between the silicon conduction band and homo levels of the molecules. The pinning of the Fermi level at the interface of metal/molecule plays a critical role in the electrical behaviour of the organicbased rectifying junctions. However, developing stable rectifying devices that can be easily processed, and have the ability for high electron mobility is challenging. The high band gap and ionization energies are the main qualities of PDI-based molecules for rectifying applications.

### 4. Conclusions

A small fatty amine-substituted perylene diimide (O-PDI) molecule can be subjected to nucleophilic substitution reactions. The synthesized molecules were characterized through various experimental techniques, including FT-IR, NMR spectroscopy, UV-visible, Tauc–Plot, thermal gravimetric analysis, and X-ray diffraction pattern (XRD), confirming the formation of O-PDI through this technique. Absorption bands of O-PDI were observed at  $\sim$  527,  $\sim$  490, and  $\sim$  459 nm, representing the vibronic absorption bands 0–0, 0–1, and 0–2 transitions, respectively, of the monomeric perylene diimide solution.

The bandgap  $(E_{g})$ , calculated using the Tauc plot, is  $\sim$  2.29 eV in the visible region, supported by cyclic voltammetric measurements. Furthermore, stability of up to 2000 °C was confirmed by TGA analysis, and the XRD measurements indicated the O-PDI phase. In addition, the rectifying behaviour exhibited by the Al/P-c-Si/O-PDI/Ag device, with a rectification ratio of  $\sim$  3470@  $\pm$  2 V, was observed, indicating a considerably good performance compared to other PDI-based rectifiers reported thus far. Thus, pronounced current rectification was revealed by the I–V characteristics. To our knowledge, such high rectification ratio values are rare in devices fabricated using non-PDI molecules.

## Conflicts of interest

There are no conflicts to declare.

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